Slotted Optical Switch

OPB806

Features:

- Non-contact switching
- Base or side mounting
- 0.125" (3.175 mm) slot width •





Description:

The OPB806 slotted optical switch consists of an infrared emitting diode (LED) and a NPN silicon phototransistor, mounted on opposite sides of a 0.125" (3.175 mm) wide slot.

The OPB806 has two sets of mounting tabs allowing Base or Side mounting of the device. The LED and phototransistor leads project from each side of the housing on 0.050" (1.27 mm) centers.

LED Peak

Phototransistor switching takes place whenever an opaque object passes through the slot.

Applications:

- Non-contact interruptive object sensing •
- Assembly line automation
- Machine automation •

2

Pin #

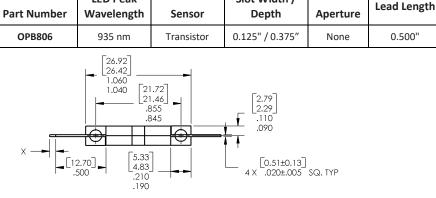
1

2

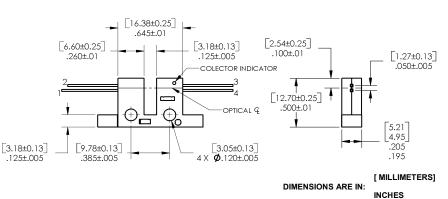
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4

- Equipment security •
- Machine safety



Slot Width /



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Description

Anode

Cathode

Collector

Emitter

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RoHS

0.500"

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Electrical Specifications

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

-40° C to +85° C
260° C
50 mA
3 A
2 V
100 mW
30 V
5 V
100 mW

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
nput Diode	(See OP165 for additional information)					
V _F	Forward Voltage	-	-	1.7	V	I _F = 20 mA
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V
Output Pho	totransistor (See OP505 for additional info	rmation)				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30	-	-	V	I _c = 100 μA
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5	-	-	V	I _E = 100 μA
I _{CEO}	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0, \text{ E}_{E} = 0$
Combined						
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	-	-	0.5	V	I _C = 200 μA, I _F = 20 mA
I _{C(ON)}	On-State Collector Current	0.4	-	-	mA	V _{CE} = 0.5 V, I _F = 20 mA

Notes:

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

- (2) Derate linearly 1.67 mW/°C above 25 ° C..
- (3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
- (4) All parameters were tested using pulse technique.

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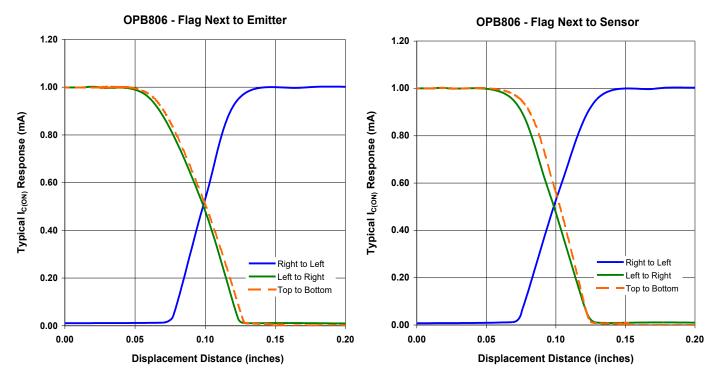
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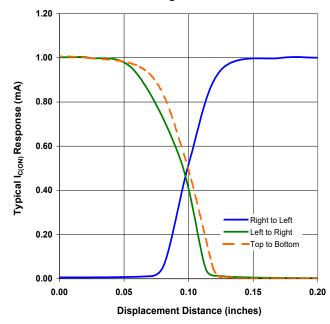
OPB806



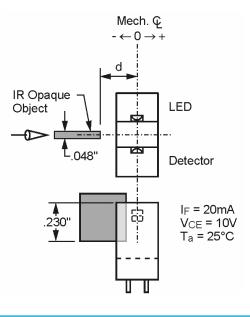
Performance



OPB806 - Flag in Middle of Slot



Test Schematic



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